SCLS169B - DECEMBER 1982 - REVISED MAY 1997

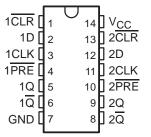
- Inputs Are TTL-Voltage Compatible
- Package Options Include Plastic Small-Outline (D), Thin Shrink Small-Outline (PW), and Ceramic Flat (W) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

description

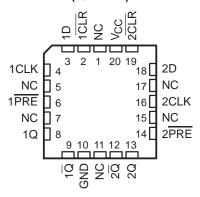
The 'HCT74 contain two independent D-type positive-edge-triggered flip-flops. A low level at the preset (PRE) or clear (CLR) inputs sets or resets the outputs regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup time requirements are transferred to the outputs on the positive-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of CLK. Following the hold-time interval, data at the D input may be changed without affecting the levels at the outputs.

The SN54HCT74 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74HCT74 is characterized for operation from -40°C to 85°C.

SN54HCT74 . . . J OR W PACKAGE SN74HCT74 . . . D, N, OR PW PACKAGE (TOP VIEW)



SN54HCT74 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

FUNCTION TABLE

	INP	OUT	-		
PRE	CLR	CLK	D	Q	Q
L	Н	Х	Х	Н	L
Н	L	X	Χ	L	Н
L	L	X	Χ	H [†]	H [†]
Н	Н	1	Н	Н	L
Н	Н	1	L	L	Н
Н	Н	L	Χ	Q ₀	Q_0

[†] This configuration is unstable; that is, it does not persist when $\overline{\mathsf{PRE}}$ or $\overline{\mathsf{CLR}}$ returns to its inactive (high) level.

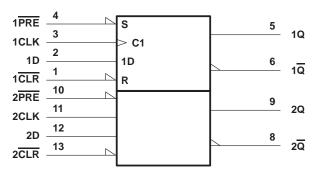


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



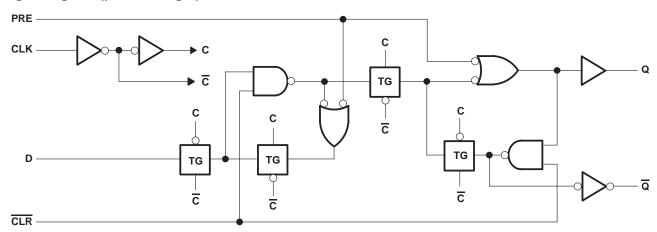
SCLS169B - DECEMBER 1982 - REVISED MAY 1997

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the D, J, N, PW, and W packages.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range‡

Supply voltage range, V _{CC}	-0.5	V to 7 V
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$) (see N	Note 1)	±20 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$) (s	see Note 1)	±20 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$		±25 mA
Continuous current through V _{CC} or GND		±50 mA
Package thermal impedance, θ_{JA} (see Note 2): D	package 1	27°C/W
N	package	78°C/W
PV	W package 1	70°C/W
Storage temperature range, T _{Stq}		o 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - 2. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.



SCLS169B - DECEMBER 1982 - REVISED MAY 1997

recommended operating conditions

			SN54HCT74			SN74HCT74			UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	ONIT
Vcc	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2		15	2			V
VIL	Low-level input voltage	V _{CC} = 4.5 V to 5.5 V	0	100	0.8	0		0.8	V
٧ _I	Input voltage		0	7	Vcc	0		VCC	V
٧o	Output voltage		0	5	VCC	0		VCC	V
t _t	Input transition (rise and fall) time		0	7	500	0		500	ns
TA	Operating free-air temperature		-55		125	-40		85	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		Voc	T _A = 25°C			SN54HCT74		SN74HCT74		UNIT
PARAMETER	TEST CO	NDITIONS	vcc	MIN	TYP	MAX	MIN MAX		MIN MAX		UNII
Vari	V _{OH} V _I = V _{IH} or V _{IL}		4.5 V	4.4	4.499		4.4		4.4		V
Voн	AI = AIH OL AIL	I _{OH} = -4 mA	4.5 V	3.98	4.3		3.7	7	3.84		٧
Va	VI = VIH or VIL	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL	v = v H oi v L	I _{OL} = 4 mA	4.5 V		0.17	0.26		0.4		0.33	V
lį	VI = VCC or 0		5.5 V		±0.1	±100		±1000		±1000	nA
Icc	$V_I = V_{CC}$ or 0,	IO = 0	5.5 V			4	2	80		40	μΑ
ΔI _{CC} †	One input at 0.5 V of Other inputs at 0 or		5.5 V		1.4	2.4	704 ₀	3		2.9	mA
Ci			4.5 V to 5.5 V		3	10		10		10	pF

This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

timing requirements over recommended operating free-air temperature range (unless otherwise noted)

			Vaa	T _A =	25°C	SN54H	ICT74	SN74H	ICT74	UNIT
			VCC	MIN	MAX	MIN	MAX	MIN	MAX	UNII
f Olash farman an			4.5 V	0	27	0	18	0	22	MHz
¹clock	f _{clock} Clock frequency		5.5 V	0	30	0	20	0	24	IVITZ
	t _w Pulse duration	PDE . OLD I	4.5 V	16		24		20		ns
1.		PRE or CLR low	5.5 V	14		21	161	18		
t _W Pulse duration	CLK high or low	4.5 V	18		27	KI	23		115	
		CLK high or low	5.5 V	16		24	0	21		
		Data	4.5 V	12		1.8		15		
1.	Setup time before CLK↑	Data	5.5 V	11		16		14		ns
^t su	t _{SU} Setup time before CLKT	DDE . OLD	4.5 V	0		& O		0		
		PRE or CLR inactive	5.5 V	0		0		0		
.	Hold time, data after CLK↑	_	4.5 V	0		0		0		no
th	noid time, data after CLK		5.5 V	0		0		0		ns

SCLS169B - DECEMBER 1982 - REVISED MAY 1997

switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	Vaa	T,	ղ = 25°C	;	SN54H	ICT74	SN74H	CT74	UNIT
	(INPUT)		(OUTPUT)	VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX
			4.5 V	27	40		18		22		MHz
fmax			5.5 V	30	46		20	(5)	24		IVITIZ
			4.5 V		21	35		53		44	
	PRE or CLR	Q or Q	5.5 V		17	31		48		40	ns
^t pd	CLK	Q or Q	4.5 V		20	28	(O)	42		35	115
	CLK	Q or Q	5.5 V		18	25	9	38		31	
		0 ~ 0	4.5 V		8	15	9	22		19	no
t _t		Q or Q	5.5 V		7	14		20		17	ns

operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per flip-flop	No load	35	pF

PARAMETER MEASUREMENT INFORMATION 3 V From Output Test High-Level 1.3 V 1.3 V **Under Test Point** Pulse 0 V C_L = 50 pF (see Note A) Low-Level 1.3 V Pulse 1.3 V **LOAD CIRCUIT** 0 V **VOLTAGE WAVEFORMS** Input 1.3 V 1.3 V **PULSE DURATIONS** ^tPHL ^tPLH ۷он 3 V In-Phase Reference 90% 1.3 V 90% Output Input 1<u>0%</u> V_{OL} 10% 0 V tsu ◆ tPHL Out-of-Data 90% 90% Phase Input Output **VOLTAGE WAVEFORMS VOLTAGE WAVEFORMS**

NOTES: A. C_L includes probe and test-fixture capacitance.

B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50~\Omega$, $t_\Gamma = 6$ ns, $t_f = 6$ ns.

SETUP AND HOLD AND INPUT RISE AND FALL TIMES

C. For clock inputs, $f_{\mbox{max}}$ is measured when the input duty cycle is 50%.

PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES

- D. The outputs are measured one at a time with one input transition per measurement.
- E. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 1. Load Circuit and Voltage Waveforms



PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and other specifications are design goals. Texas Instruments reserves the right to change or discontinue these products without notice.

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.

Copyright © 1998, Texas Instruments Incorporated